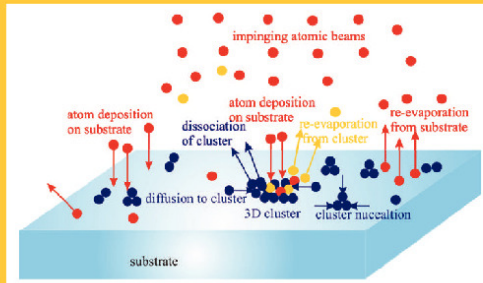




Abdelhamid Abdelrehim Mahmoud Elshaer (Autor)
Molecular Beam Epitaxy Growth and Characterization of ZnO-based layers and Heterostructures

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